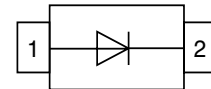
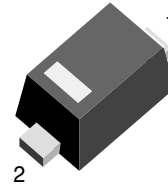


RF PIN Diode - Single in SOD-523

Description

With the very low forward resistance combined with a low reverse capacitance the BAR65V-02V is ideal for RF-signal switching. Depending on the forward current (I_F) the forward resistance (r_f) can be reduced to only a few hundred m Ω . In the reverse mode the isolation capacitance is less than 1 pF. Due to its low loss behaviour this PIN diode is most suitable for switching of transmitter and receiver in wireless and mobile systems as well as for band switching in TV-tuner systems.



16863

Features

- Space saving SOD-523 package with low series inductance
- Very low forward resistance
- Small reverse capacitance
- Lead (Pb)-free component
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC



Mechanical Data

Case: SOD-523 Plastic case

Weight: approx. 1.6 mg

Cathode Band Color: Laser marking

Packaging Codes/Options:

GS18 / 10 k per 13" reel (8 mm tape), 10 k/box

GS08 / 3 k per 7" reel (8 mm tape), 15 k/box

Applications

For frequency up to 3 GHz

RF-signal switching

Mobile, wireless and TV-Applications

Parts Table

Part	Ordering code	Marking	Remarks
BAR65V-02V	BAR65V-02V-GS18 or BAR65V-02V-GS08	E	Tape and Reel

Absolute Maximum Ratings

$T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified

Parameter	Test condition	Symbol	Value	Unit
Reverse voltage		V_R	30	V
Forward current		I_F	100	mA
Junction temperature		T_j	150	$^{\circ}\text{C}$
Storage temperature range		T_{stg}	- 55 to + 150	$^{\circ}\text{C}$

Thermal Characteristics

$T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified

Parameter	Test condition	Symbol	Value	Unit
Junction soldering point		R_{thJS}	100	K/W

Electrical Characteristics

$T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified

Parameter	Test condition	Symbol	Min	Typ.	Max	Unit
Reverse voltage	$I_R = 10\text{ }\mu\text{A}$	V_R	30			V
Reverse current	$V_R = 20\text{ V}$	I_R			20	nA
Forward voltage	$I_F = 100\text{ mA}$	V_F			1.1	V
Diode capacitance	$f = 1\text{ MHz}$, $V_R = 0$	C_D		0.65		pF
	$f = 1\text{ MHz}$, $V_R = 1\text{ V}$	C_D		0.55	0.9	pF
	$f = 1\text{ MHz}$, $V_R = 3\text{ V}$	C_D		0.50	0.8	pF
Forward resistance	$f = 100\text{ MHz}$, $I_F = 1\text{ mA}$	r_f		1		Ω
	$f = 100\text{ MHz}$, $I_F = 5\text{ mA}$	r_f		0.6	0.95	Ω
	$f = 100\text{ MHz}$, $I_F = 10\text{ mA}$	r_f		0.5	0.9	Ω
Charge carrier life time	$I_F = 10\text{ mA}$, $I_R = 6\text{ mA}$, $i_R = 3\text{ mA}$	t_{rr}		175		ns

Typical Characteristics ($T_{amb} = 25\text{ }^{\circ}\text{C}$ unless otherwise specified)

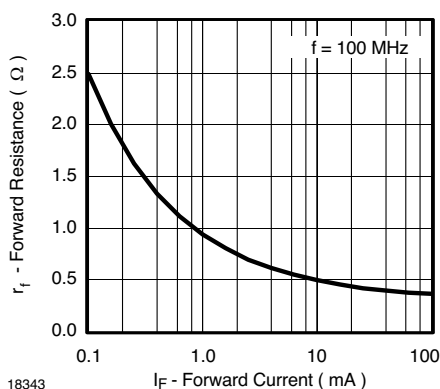


Figure 1. Forward Resistance vs. Forward Current

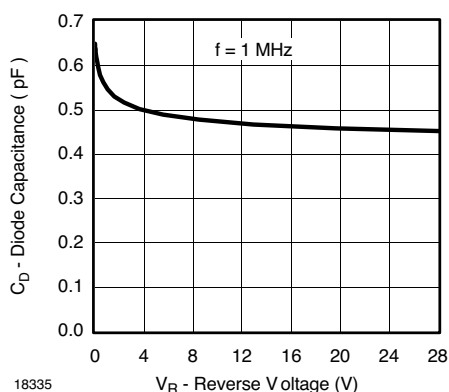


Figure 2. Diode Capacitance vs. Reverse Voltage

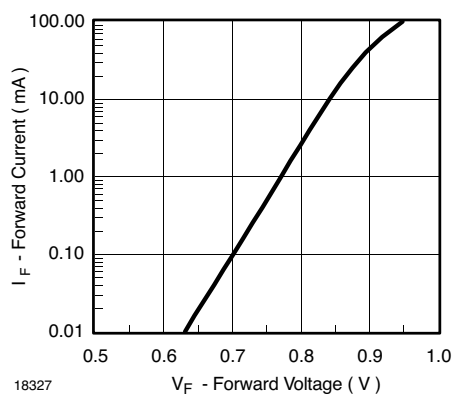


Figure 3. Forward Current vs. Forward Voltage

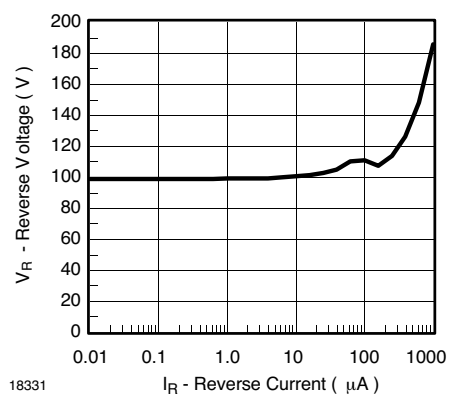


Figure 4. Reverse Voltage vs. Reverse Current

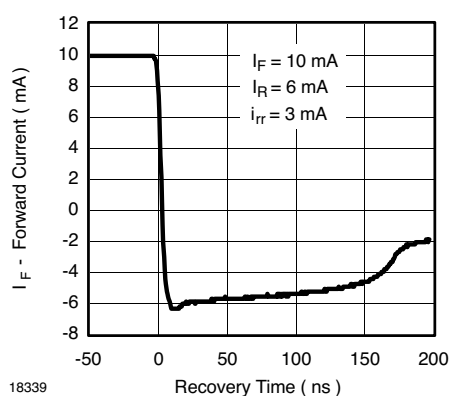
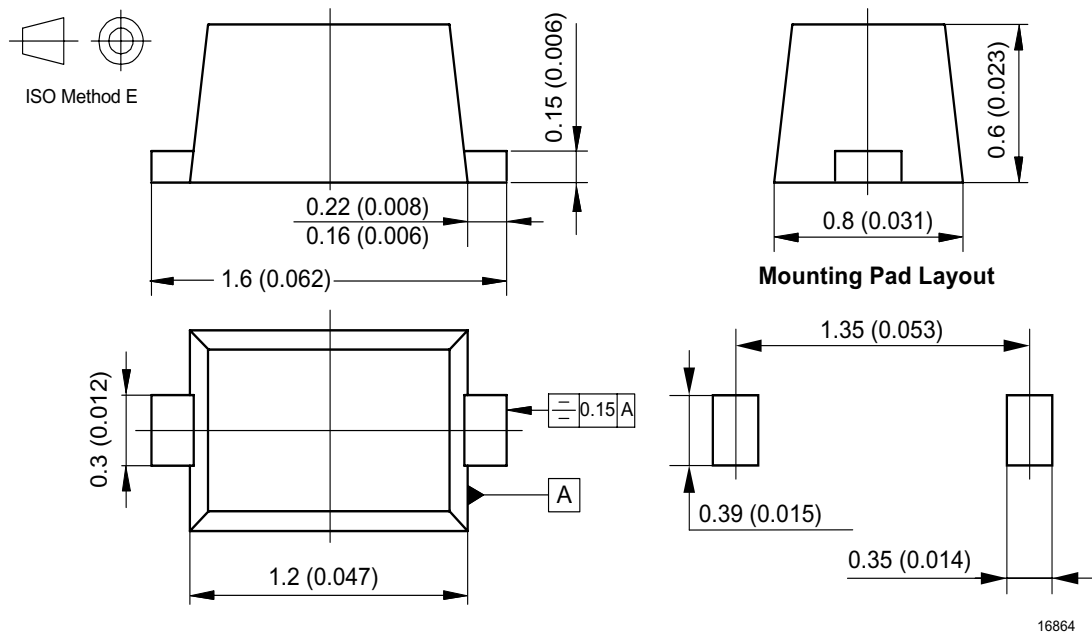


Figure 5. Typical Charge Recovery Curve

Package Dimensions in mm (Inches)





Ozone Depleting Substances Policy Statement

It is the policy of Vishay Semiconductor GmbH to

1. Meet all present and future national and international statutory requirements.
2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design
and may do so without further notice.

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay Semiconductors products for any unintended or unauthorized application, the buyer shall indemnify Vishay Semiconductors against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

Vishay Semiconductor GmbH, P.O.B. 3535, D-74025 Heilbronn, Germany



Notice

Specifications of the products displayed herein are subject to change without notice. Vishay Intertechnology, Inc., or anyone on its behalf, assumes no responsibility or liability for any errors or inaccuracies.

Information contained herein is intended to provide a product description only. No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document. Except as provided in Vishay's terms and conditions of sale for such products, Vishay assumes no liability whatsoever, and disclaims any express or implied warranty, relating to sale and/or use of Vishay products including liability or warranties relating to fitness for a particular purpose, merchantability, or infringement of any patent, copyright, or other intellectual property right.

The products shown herein are not designed for use in medical, life-saving, or life-sustaining applications. Customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Vishay for any damages resulting from such improper use or sale.